Synthesis and Properties of Isomerically Pure Anthrabisbenzothiophenes

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The synthesis of three heptacyclic heteroacenes is described, namely anthra[2,3-*b*:7,6-*b*']bis[1]benzothiophenes (ABBTs). A stepwise sequence of aldol reactions provides regiochemical control, affording only the *syn*-isomer. The ABBTs are characterized by X-ray crystallography, UV-vis absorption, and emission spectroscopy, as well as cyclic voltammetry. Field effect transistors based on solution-cast thin films of ABBT derivatives exhibit charge-carrier mobilities of as high as 0.013 cm²/(V s).

Over the past decade or so, there have been significant advances in the development of acene derivatives for semiconductor applications.¹ Studies of these new materials demonstrate remarkable potential for their use in, for

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example, organic field effect transistors and photovoltaics.¹ The formation of heteroacenes, through the formal incorporation of heteroatoms into a hydrocarbon acene skeleton, allows for tuning of electronic properties, as well as the realization of new chromophore structures.²



Figure 1. Structures of *syn*- and *anti*-ADT (1 and 2, respectively) and benzannulated relatives *syn*- and *anti*-ABBT (3 and 4, respectively).

Anthradithiophenes (ADTs, 1-2, Figure 1) are a subclass of heteroacenes that often show promising semiconducting properties similar to that of pentacene.^{3a} Furthermore,

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when appropriately functionalized, ADTs normally show improved stability relative to pentacenes.^{2e,3b,4} To date, however, ADT and its derivatives have typically been synthesized and studied as a mixture *syn-* and *anti*-isomers (1 and 2, respectively),³ although the study of isomerically pure ADTs has recently been achieved in two cases.^{5,6}

Scheme 1. Synthesis of *syn*-ABBTs **5a**-c



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Intrigued by the performance of ADTs in semiconducting devices and challenged by the issue of obtaining isomerically pure chromophores that might offer decreased disorder compared to the isomeric ADT mixtures, we targeted the synthesis of a new class of ADT analogues, anthrabis[1]benzothiophenes (ABBTs, Figure 1). The additional aromatic ring at each benzothiophene moiety of the ABBTs results in a slightly bent or curved structure. It was thus expected that disordered solid-state packing observed for ADTs should be avoided for ABBTs via more discriminate interactions in the solid, based on both steric and electronic demands. Similar to ADTs, however, there are two possible isomers for ABBTs, the *syn*- and *anti*-isomers (**3** and **4**, respectively). In the present study, we report the selective synthesis and properties of *syn*-ABBTs **5a**-c (Scheme 1).

The synthesis of ABBTs 5a-c began with commercially available thianaphthene-3-carboxaldehyde (6). Protection of the aldehyde as an acetal using 1,2-ethylene glycol afforded 7. Lithiation of 7 followed by reaction with ethyl formate provided the masked dialdehyde 8 in 70% yield. A 2-fold aldol condensation of 9 with 8 provided intermediate 10 in 94% yield.⁷ Global deprotection of the three acetal groups of 10 was accomplished with catalytic $In(OTf)_3$ (12 mol %) under reflux in acetone. These same conditions effected the subsequent intramolecular aldol condensation, leading to the one pot formation of quinone 11 in 67% yield from 10.⁸ Isolated as a brown solid, quinone 11 is sparingly soluble in common organic solvents. Nevertheless, reaction of 11 with various lithium acetylides could be accomplished in THF at low temperature and afforded diols 12a-c in moderate yields. Aromatization was accomplished in the usual way with SnCl₂·2H₂O in the presence of 10% aq H₂SO₄, providing ABBTs **5a-c** in good yield.

Table 1. Thermal Properties of ABBTs 5a-c										
			DSC decomposition ^{a}							
compd	$\mathrm{TGA}T_{\mathrm{d}}/^{\mathrm{o}}\mathrm{C}^{a}$	$\mathrm{DSC} \ \mathrm{mp}/^{\!\circ}\mathrm{C}^a$	onset/°C	peak/°C						
5a	415	414	414	415						
5 b	360	319	347	360						
5 c	380	242	345	355						

^a Measured under nitrogen atmosphere.

ABBT **5a** has limited solubility in common solvents, while derivatives **5b**,**c** show much improved solubility because of the larger trialkylsilyl groups and can be easily dissolved in solvents such as THF, CH_2Cl_2 , and $CHCl_3$. The constitution of the trialkylsilyl group also affects the thermal properties as assessed by differential scanning calorimetry (DSC) and thermogravimetric analysis (TGA, Table 1). *i*-Pr₃Si-substituted ABBT **5a** has the highest

⁽⁷⁾ While the stereochemistry about the olefins formed from the aldol condensation has not been assigned, NMR spectroscopic data suggest only one isomer.

⁽⁸⁾ Quinone **11** has been previously synthesized as a mixture of *syn*and *anti*-isomers using a significantly different approach; see: Reid, W.; Bender, H. *Chem. Ber.* **1956**, *89*, 1574–1577.

melting point (414 °C), which is followed immediately by decomposition. *i*-Bu₃Si- and *n*-Bu₃Si-substituted ABBTs **5b** and **5c** have progressively lower melting points, while their decomposition points are essentially identical. Finally, there is good agreement between the decomposition temperatures as measured by TGA and DSC analysis, indicating that thermal decomposition is accompanied by weight loss.



Figure 2. Solid-state packing of (a) 5a, (b) 5b, and (c) 5c; carbon = gray, silicon = red, sulfur = yellow.

Not surprisingly, the shape and size of the pendent trialkylsilyl groups also impact the solid-state packing of ABBTs 5a-c (Figure 2).⁹ Single crystals for each compound have been obtained from CH₂Cl₂ solutions layered with acetone that were allowed to evaporate at 4 °C.¹⁰ In the solid state, ABBTs 5a and 5c arrange as centrosymmetric dimeric pairs, with an interplanar spacing between adjacent molecules of the pair that is nearly identical for both structures (3.35-3.36 Å). The spacing that separates one dimeric pair from its neighbor is 3.40 A for 5a and 3.38 Å for 5c. For both 5a and 5c, the dimeric pairs then form a 1-dimensional (1-D) slipped π -stacking arrangement. The π -stacked arrays of **5b**, on the other hand, afford 1-D channels with very limited acene overlap at an interplanar spacing of 3.44 Å. This is due to edge-to-face interactions by neighboring π -stacked channels, similar to the "sandwich herringbone" motif seen in pentacene semiconductors.

UV-vis absorption and emission spectra of 5a-c were acquired in CH₂Cl₂ (Table 2), and maxima are identical within ± 1 nm (representative spectra for 5c are shown in Figure 3).¹¹ Briefly, ABBTs have a $\lambda_{max} = 542$ nm, which is blue-shifted by 13 nm compared to the analogous TIPS-ADT derivative, measured as a mixture of *syn*- and *anti*-isomers.^{2c} Two weak mid-energy absorption bands are observed at $\lambda = 442$ and 417 nm, while in the UV region the most significant absorption band is found at $\lambda = 350$ nm. The emission spectra of 5a-c show $\lambda_{max,em}$ at 548–549 nm. In each case, the Stokes shift is very small (6–7 nm, 202–235 cm⁻¹).

The λ_{max} values for **5a**-**c** taken from UV-vis spectra of thin films cast from CH₂Cl₂ all show a red shift versus the solution-state values. The bathochromic shift is largest for **5a** (36 nm), while smaller shifts of 15 nm and 6 nm are observed for **5c** and **5b**, respectively. The large red shift observed for **5a** is consistent with the solid-state packing from X-ray crystallographic analysis in which **5a** has improved π -stacking overlap compared to **5b** and **5c**.¹¹

Cyclic voltammetry for **5a**–**c** establish the redox behavior and electrochemical gap, E_g^{electro} (Table 2).¹¹ Within the electrochemical window scanned (1.0 to -1.8 V vs Ag/AgNO₃ electrode), only one oxidation (ca. 0.55 V vs Fc/Fc⁺) and one reduction (ca. -1.68 V vs Fc/Fc⁺) event are observed for each ABBT derivative, and all are reversible, except for the signals of 5a which are quasi-reversible. The gap calculated from this data for 5a–c (2.22–2.23 eV) is in good agreement with the optical HOMO–LUMO gaps of 2.21–2.22 eV estimated from solution-state UV–vis spectroscopy (Table 2).

Field effect transistors (FETs) based on thin films of **5b** and **5c** drop-cast from solution (1 wt % from toluene and chlorobenzene, respectively) provide for an evaluation of

(11) See the Supporting Information for details.

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⁽¹⁰⁾ Crystallographic data for 5a (CCDC 849435): C₄₈H₅₄S₂Si₂, $M_{\rm r} = 751.21$; crystal dimensions (mm) $0.45 \times 0.12 \times 0.11$; triclinic $M_{\rm r} = /51.21$; crystal dimensions (mm) $0.45 \times 0.12 \times 0.11$; triclinic space group $P\overline{1}$ (No. 2); a = 11.317(2) Å, b = 12.747(3) Å, c = 15.369(3) Å; $\alpha = 75.186(3)^{\circ}$, $\beta = 78.547(3)^{\circ}$, $\gamma = 84.000(3)^{\circ}$; V = 2097.3(8) Å³; Z = 2; $\rho_{\rm calcd} = 1.190$ g cm⁻³; $\mu = 0.216$ mm⁻¹; $\lambda = 0.71073$ Å; T = -100 °C; $2\theta_{\rm max} = 51.44^{\circ}$; total data collected = 15556; $R_1 = 0.0540$ [5019 observed reflections with $F_o^2 \ge 2\sigma(F_o^2)$]; w $R_2 = 0.1530$ for 469 vari-ables, 7943 unique reflections, and five restraints; residual electron density = 0.415 and -0.362 e Å⁻³. The C46A-C47A, C46A-C48A, C46B-C47B, and C46B-C48B distances within the dicordered iscore C46B-C47B, and C46B-C48B distances within the disordered isopropyl group were constrained to be equal (within 0.03 Å) to a common refined value. The C47A····C48A and C47B····C48B distances were constrained to be equal (within 0.03 Å) during refinement. Crystal-lographic data for **5b** (CCDC 849436): $C_{54}H_{66}S_2Si_2$, $M_r = 835_37$; crystal dimensions (mm) $0.56 \times 0.13 \times 0.10$; triclinic space group $P\overline{1}$ (No. 2); a = 11.1453(11) Å, b = 16.4944(16) Å, c = 26.181(3) Å; a = 88.4584(13)^\circ, β = 85.4059(14)°, γ = 89.7663(13)°; V = 4795.7(8) Å³; Z = 4; ρ_{calcd} = 1.157 g cm⁻³; μ = 0.196 mm⁻¹; λ = 0.71073 Å; T = -100 °C; $2\theta_{max}$ = 51.80°; total data collected = 18532; R_1 = 0.052 ρ 12672 observed reflections with $F_o^2 \ge 2\sigma$ (F_o^2)]; w $R_2 = 0.1527$ for 1295 variables, 18532 unique reflections, and 51 restraints; residual electron density = 0.598 and -0.602 e Å⁻³. Distances involving the disordered triisobutylsilyl groups were restrained during refinement; see the Supporting Information. Crystallographic data for 5c (CCDC 849437): $C_{54}H_{66}S_{2}Si_{2}$, $M_{r} = 835.37$; crystal dimensions (mm) 0.49 × 0.17 × 0.11; triclinic space group *P*I (No. 2); a = 8.9292(4) Å, b =15.2194(6) Å, c = 18.4144(8) Å; $\alpha = 83.0261(5)^\circ$, $\beta = 76.3552(5)^\circ$, $\gamma = 88.7465(5)^\circ$; V = 2413.78(18) Å³; Z = 2; $\rho_{calcd} = 1.149$ g cm⁻³; $\mu = 0.194$ mm⁻¹; $\lambda = 0.71073$ Å; T = -100 °C; $2\theta_{max} = 52.80^\circ$; total data collected = 19417; $R_1 = 0.0451$ [7756 observed reflections with $F_0^2 \ge 2\sigma$ (F_0^2)]; w $R_2 = 0.1395$ for 560 variables and 9850 unique reflections; residual electron density = 0.619 and -0.376 e Å⁻

Table 2. Optoelectronic and Electrochemical Properties of ABBT 5a-c											
compd	$\begin{array}{c} \lambda_{max} \\ (in \ CH_2 Cl_2) / nm \end{array}$	$\lambda_{\rm max}$ (film)/nm ^a	λ_{onset} (film) /nm ^a	$\begin{array}{c} \lambda_{\max,em} \\ (\text{in } \operatorname{CH}_2\operatorname{Cl}_2)\!/\!\mathrm{nm}^b \end{array}$	Stokes shift/nm	$E_{ m g}^{ m opt}$ (in CH ₂ Cl ₂)/eV ^c	$E_{ m g}^{ m electro}$ (in CH ₂ Cl ₂)/eV ^d	$\frac{E_{\rm ox}}{({\rm in~CH_2Cl_2})/{\rm V}^d}$	$E_{\rm red}$ (in CH ₂ Cl ₂)/V ^d		
5a	542	578	613	548	6	2.22	2.23	0.55^{e}	-1.68^{e}		
5b 5c	542 542	$\begin{array}{c} 548 \\ 557 \end{array}$	$\begin{array}{c} 624 \\ 613 \end{array}$	549 548	7 6	$2.21 \\ 2.22$	$\begin{array}{c} 2.23 \\ 2.22 \end{array}$	0.54^{f} 0.55^{f}	-1.69^{f} -1.67^{f}		

^{*a*} Film from CH₂Cl₂. ^{*b*} Measured using λ_{exc} 504 nm. ^{*c*} The value used as the absorption edge corresponds to the lowest-energy absorption wavelength with a molar absorption coefficient $\varepsilon \ge 1000 \text{ L} \cdot \text{mol}^{-1} \cdot \text{cm}^{-1}$. ^{*d*} Cyclic voltammetry was performed in CH₂Cl₂ solutions containing 0.1 M *n*-Bu₄NPF₆ as supporting electrolyte. The potential values (*E*) were calculated using the following equation: $E = (E_{pc} + E_{pa})/2$, where E_{pc} and E_{pa} correspond to the cathodic and anodic peak potentials, respectively. Potentials are referenced to the ferrocene/ferrocenium (Fc/Fc⁺) couple used as an internal standard. All potentials represent a one-electron reduction or oxidation event. ^{*e*} Measured at a scan rate of 200 mV \cdot s⁻¹. ^{*f*} Measured at a scan rate of 150 mV \cdot s⁻¹.



Figure 3. UV–vis spectrum of **5c** in CH₂Cl₂ (235–585 nm). Inset: expansion of low energy region of UV–vis absorption spectra (385–585 nm) and normalized emission spectra of **5c** in CH₂Cl₂ (510–710 nm) using $\lambda_{exc} = 504$ nm.

the charge transport properties. Because of low solubility and noncontinuous films, **5a** was not tested in FETs. For ABBTs **5b** and **5c**, both derivatives formed needle-like structures with poor coverage of the channel region of the device as expected from their 1-D π -stacked nature. ABBT **5c** exhibits reasonable hole transport considering the film morphology, with charge-carrier mobilities as high as 1.3×10^{-2} cm²/(V s). Hole mobilities for films of **5b** were lower, with a maximum of $2.2 \times 10^{-5} \text{ cm}^2/(\text{V s})$. The different behavior of **5b** and **5c** roughly correlates with the lesser degree of electronic interaction suggested by the solid-state UV-absorption spectrum (i.e., a smaller red shift vs solution-state data for **5b** relative to **5c**).¹¹

In summary, a new class of heteroacene chromophores has been synthesized in isomerically pure form, namely the anthra[2,3-*b*:7,6-*b*']bis[1]benzothiophenes (*syn*-ABBTs. The choice of the ethynyl groups laterally appended to acene influences the thermal properties, as well as the solidstate packing. Finally, FETs fabricated from **5b** and **5c** afford moderate mobilities in the case of **5c**, consistent with better π -stacking suggested for this compound through the UV-vis analyses.

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Supporting Information Available. Experimental procedures, spectroscopic data, ¹H and ¹³C NMR spectra for all new compounds, and CIF files (5a-c). This material is available free of charge via the Internet at http:// pubs.acs.org.